TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WBD125AFK

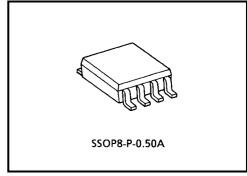
#### **Dual Bus Switch with Level Shift**

The TC7WBD125AFK is a low on-resistance, high-speed CMOS 2-bit bus switch. This bus switch allows the connections or disconnections to be made with minimal propagation delay while maintaining Low power dissipation which is the feature of CMOS.

When output enable (OE) is at low level, the switch is on; when at high level, the switch is off.

The device is enable to realize the shift of signal level from 5 V to 3.3 V.

All inputs are equipped with protector circuits to protect the device from static discharge.



Weight: 0.01 g (typ.)

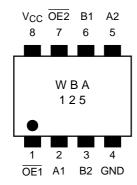
#### **Features**

- Operating voltage:  $V_{CC} = 4.5 \sim 5.5 \text{ V}$
- High speed operation:  $t_{pd} = 0.32 \text{ ns (max)}$
- Ultra-low on resistance:  $R_{ON} = 5 \Omega$  (typ.)
- Electro-static discharge (ESD) performance: ±200 V or more (JEITA)

±2000 V or more (MIL)

- TTL level input (control input)
- Low Power Dissipation: Icc = 10 μA (max.)
- Package: US8

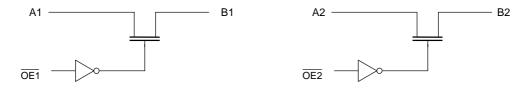
#### Pin Assignment (top view)



### **Truth Table**

Inputs	Function		
ŌE	Function		
L	A port = B port		
Н	Disconnect		

### **System Diagram**



## **Maximum Ratings**

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5~7.0	V
Control pin input voltage	V <sub>IN</sub>	-0.5~7.0	V
Switch terminal I/O voltage	Vs	-0.5~7.0	V
Clump diode current	I <sub>IK</sub>	-50	mA
Switch I/O current	IS	128	mA
Power dissipation	PD	200	mW
DC V <sub>CC</sub> /GND current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65~150	°C

# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	4.5~5.5	V
Control pin input voltage	V <sub>IN</sub>	0~5.5	V
Switch I/O voltage	Vs	0~5.5	V
Operating temperature	T <sub>opr</sub>	-40~85	°C
Control pin input rise/fall time	dt/dv	0~10	ns/V

#### **Electrical Characteristics**

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#### DC Characteristics ( $Ta = -40 \sim 85$ °C)

Charac	teristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Typ. (Note 1)	Max	Unit			
Input voltage	"H" level	V <sub>IH</sub>		-	4.5~5.5	2.0	_	_	V			
Input voltage	"L" level	V <sub>IL</sub>	_	-	4.5~5.5	_	_	0.8	v			
High lovel outp	ut voltogo		IOH- 1A		4.75	2.3	2.8	3.2				
High-level outp	(Note 2)	V <sub>OH</sub>	IOH=-1μA V <sub>IS</sub> = V <sub>CC</sub>		5.0	2.5	3.0	3.4	V			
	(Note 2)		VIS = VCC		5.25	2.7	3.2	3.6				
Input leakage of	current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5 V		4.5~5.5	_	_	±1.0	μА			
Power off leaka	age current	l <sub>OFF</sub>	A, B, $\overline{\text{OE}} = 0 \sim 5.5 \text{ V}$		0	_	_	±1.0	μА			
Off-STATE leal (switch off)	kage current	I <sub>SZ</sub>	A, B = 0~5.5 V, $\overline{OE} = V_{CC}$		4.5~5.5	_	_	±1.0	μА			
		D		l. 64 m A	4.5	_	5	9				
					V 0V	$V_{IS} = 0 V$	I <sub>IS</sub> = 64 mA	4.75	_	5	8	-
ON resistance			VIS = 0 V	La 20 mA	4.5	_	5	9	Ω			
	(Note 3)	R <sub>ON</sub>		$I_{IS} = 30 \text{ mA}$	4.75	_	5	8	52			
			V 22V I 15 m	^	4.5	_	35	65				
			$V_{IS} = 2.3 \text{ V}, I_{IS} = 15 \text{ mA}$		4.75	_	35	50				
Quiescent supp	oly current	ICC	VIN = VCC or GND,I <sub>OUT</sub> = 0		5.5	_	_	10	μА			
Increase in I <sub>CC</sub>	per input	Δlcc	V <sub>IN</sub> = 3.4 V (one input)		5.5	_	_	2.5	mA			

Note 1: Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $Ta = 25^{\circ}C$ .

Note 2: It recommends that this device uses Pull-up resistance when adding and using resistance for an output terminal. Since it couses to drop a VOH voltage level when using Pull-down resistance for an output terminal.

Note 3: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

#### AC Characteristics ( $Ta = -40 \sim 85$ °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time (bus to bus)	t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2 (Note 4)	4.5	١	0.32	ns
Output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 3	4.5		4.5	ns
Output disable time	t <sub>pLZ</sub> t <sub>pHZ</sub>	Figure 1, Figure 3	4.5		5.0	ns

Note 4: The propagation delay time is calculated by the RC (on-resistance and load capacitance) time constant.

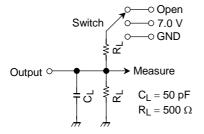
#### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Control pin input capacitance	C <sub>IN</sub>	(Note 5)	5.0	3	pF
Switch terminal capacitance	C <sub>I/O</sub>	$\overline{OE} = V_{CC}$ (Note 5)	5.0	10	pF

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Note 5: This parameter is guaranteed by design.

#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	7.0 V		
t <sub>pHZ</sub> , t <sub>pZH</sub>	Open		

Figure 1

#### **AC Waveform**

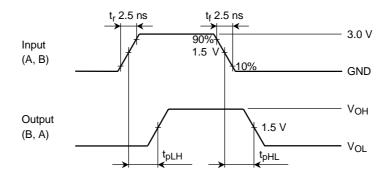


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

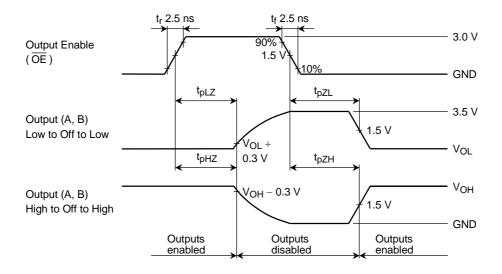
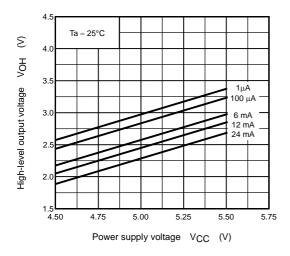
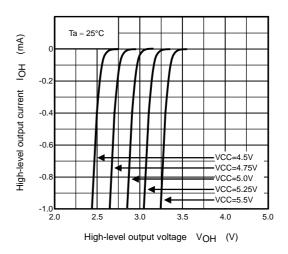
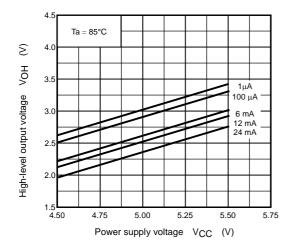


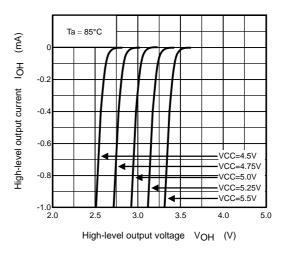
Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

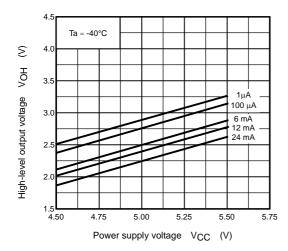
### V<sub>OH</sub> – V<sub>CC</sub> Characteristics (typ.)











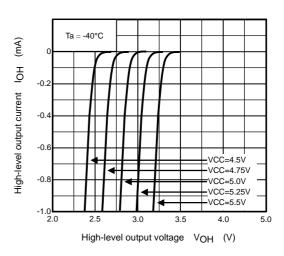


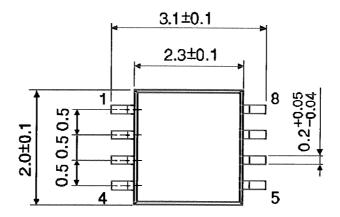
Figure 4

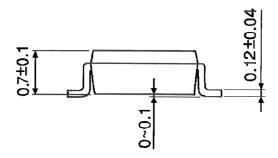
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### **Package Dimensions**

**TOSHIBA** 

SSOP8-P-0.50A Unit: mm





Weight: 0.01 g (typ.)

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